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## NSN 5962-01-394-4646 Memory Microcircuit - Page 1 of 1 **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Pin grid array **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Current Rating Per Characteristic:** 50.00 milliamperes forward current, nonrepetitive, peak total value absolute **Terminal Surface Treatment:** Solder **Product Name:** 10, 000 gate pal Voltage Rating And Type Per Characteristic: 5.0 volts applied **Time Rating Per Chacteristic:** 6.00 nanoseconds input to output access Memory Device Type: Pal **Special Features:** Actual **Terminal Type And Quantity:**

196 pin

Shelf Life:

N/a

Unit Of Measure:

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**Demilitarization:** 

No

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